

DC–24 GHz 0.5W Self-Biased Single Positive Supply Distributed Power Amplifier

Product Overview

MMA052PP45 is a gallium arsenide (GaAs) monolithic microwave integrated circuit (MMIC) pseudomorphic highelectron-mobility transistor (pHEMT) distributed self-biased amplifier in plastic package form that operates between DC and 24 GHz. It is ideal for test instrumentation, wideband military and space applications. The amplifier provides a 14 dB of gain with a rising slope, 3.5 dB noise figure, output IP3 of 35 dBm, and 28 dBm of output power at 3dB gain compression at 10 GHz. The MMA052PP45 amplifier features RF I/Os that are internally matched to 50 Ω , which is ideal for any surface mount technology (SMT) assembly equipment.

Key Features

- **Broadband performance: DC to 24 GHz**
- **Psat: 28 dBm**
- **Gain: 14 dB with positive Gain Slope**
- **High IP3: 35 dBm**
- **Single Positive Supply: 9V at 310 mA**
- **50 Ω matched I/O**
- **4.5 mm $\times$ 4.5 mm, 32L plastic QFN Passivated space-qualified process listed on EPPL007-38**

Functional Block Diagram

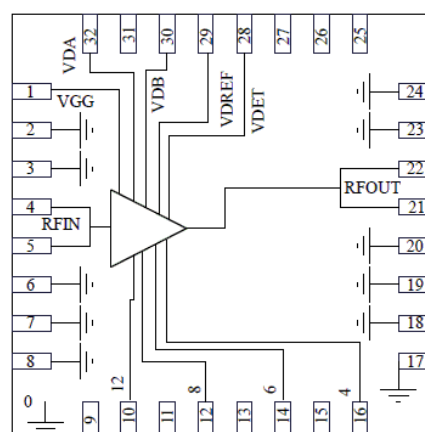


Figure 1 - Gain, IM3, Psat Performances

Applications

- Test and measurement instrumentation
- Military, EW, ECM, RADAR and space
- Telecom infrastructure
- Wideband microwave radios

Performance Overview

Parameter	Typ.	Units
Operational frequency range	DC-24	GHz
Gain	14	dB
Psat	+28	dBm
IM3 @ 20dBm	-33	dBc
Current @ +9V Supply	310	mA

Export Classification: EAR-99

Contents

1. Electrical Specifications3

1.1 Typical Electrical Performance3

1.2 Absolute Maximum Ratings.....4

1.3 Typical Performance Curves4

1.1.1 Typical Performances vs. Temperature.....4

1.1.2 Typical Performances vs. Bias..... 11

1.1.3 Typical Performances vs. Output Power..... 14

2. Package Specifications 17

3. Application Circuits: Eval PCB 19

4. Handling Recommendations..... 22

5. Ordering Information..... 22

5.1 Packing Information..... 22

1. Electrical Specifications

1.1 Typical Electrical Performance

Table 1 - Typical Electrical Performance at 25 C, Vdd=9V, Idd=310 mA (Unless otherwise mentioned)

Parameter	Frequency Range	Min	Typ.	Max	Units
Frequency range		DC		24	GHz
Gain	DC – 6 GHz	12	14		dB
	6 GHz – 12 GHz	13	14.5		
	12 GHz – 24 GHz	14	15.5		
Gain flatness	4 GHz – 12 GHz		± 1		dB
	12 GHz – 24 GHz		± 0.7		
Noise figure	2 GHz – 6 GHz		5		dB
	6 GHz – 12 GHz		3.5		
	12 GHz – 24 GHz		4.5		
Input return loss	DC – 6 GHz		15		dB
	6 GHz – 12 GHz		15		
	12 GHz – 24 GHz		12		
Output return loss	DC – 6 GHz		14		dB
	6 GHz – 12 GHz		14		
	12 GHz – 24 GHz		12		
P1dB	DC – 6 GHz	25	27		dBm
	6 GHz – 12 GHz	25	27		
	12 GHz – 20 GHz	24.5	26		
	20 GHz – 24 GHz	24	25.5		
Psat (Measured at 3dB Gain Compression)	DC – 6 GHz		29		dBm
	6 GHz – 12 GHz		28		
	12 GHz – 20 GHz		27.5		
	20 GHz – 24 GHz		27		
OIP3	DC–6 GHz		36		dBm
	6 GHz–12 GHz		35		
	12 GHz – 24 GHz		32		
IM3 @ 20dBm	DC–6 GHz		-35		dBc
	6 GHz–12 GHz		-33		
	12 GHz – 24 GHz		-26		
Phase Noise					dBm/Hz
OIP2(low) (2-nd Order Intercept point F2-F1)			57		dBm
VDD (drain voltage supply)			9	11	V
IDD (drain current)			310	400	mA

1.2 Absolute Maximum Ratings

The following table shows the absolute maximum ratings of the MMA052PP45 device at 25 °C, unless otherwise specified. Exceeding one or any of the maximum ratings potentially could cause damage or latent defects to the device.

Table 2 - Absolute Maximum Ratings

Parameter	Rating
Drain bias voltage (V_{DD})	12 V
Gate bias voltage (V_G)	-2 V to 0.5 V
RF input power (P_{in})	24 dBm (or 6 dB Compression)
Channel temperature	165 °C
V_{DD} current (I_{DD})	400 mA
DC power dissipation ($T = 85\text{ °C}$)	4.8 W
Thermal resistance	15°C/W
Storage temperature	-65 °C to 150 °C
Operating temperature	-55 °C to 85 °C



ESD Sensitive Device

1.3 Typical Performance Curves

1.1.1 Typical Performances vs. Temperature

The following graphs show the typical performance curves of the MMA052PP45 device at 25 °C vs. Bias conditions; measurements performed using application circuit shown on Figure 71 - below. Currents were set by States according to Table 3-3

Figure 1 - Gain vs. Temperature @ 5V/220mA

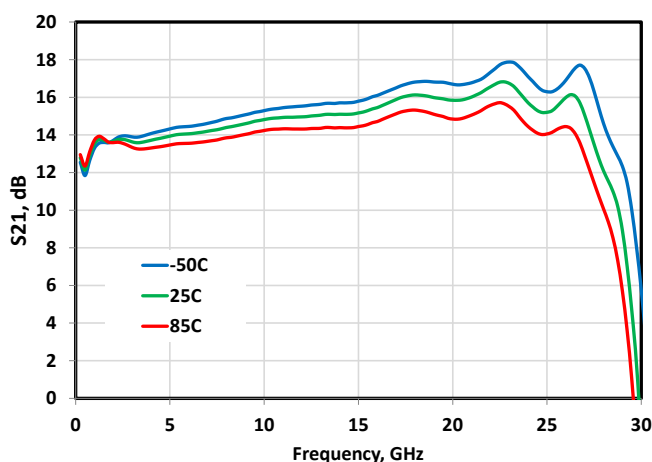


Figure 2 - Gain vs. Temperature @ 8V/270mA

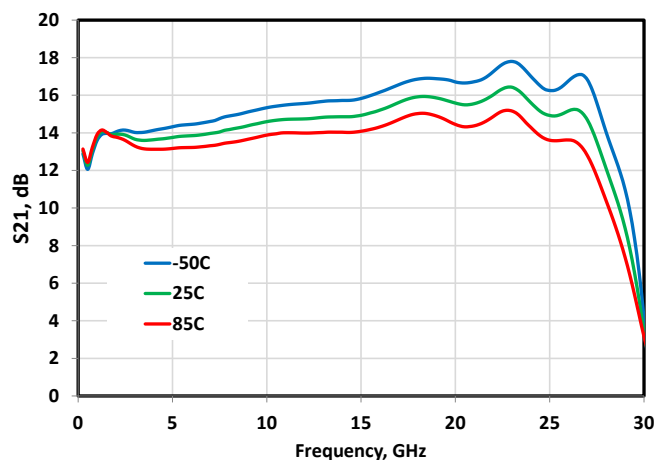


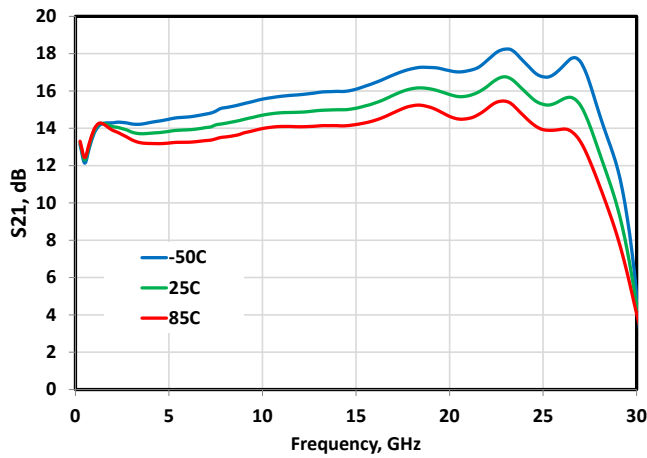
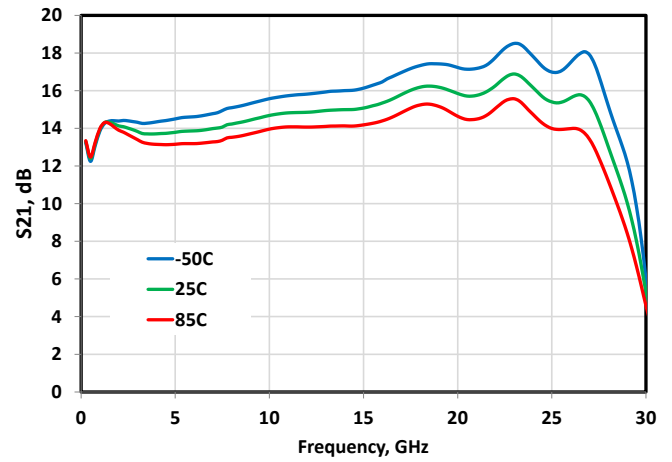
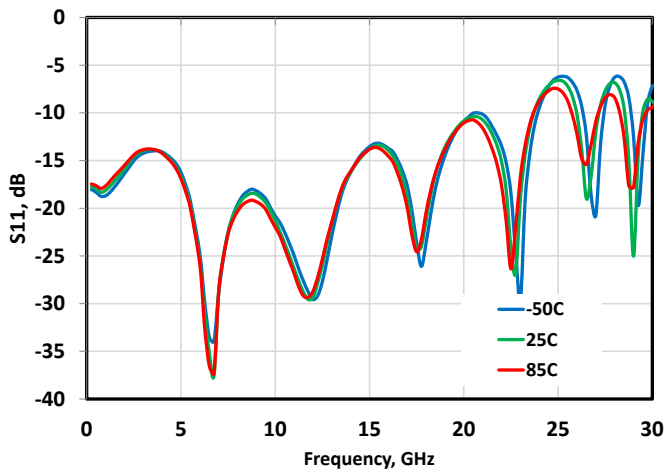
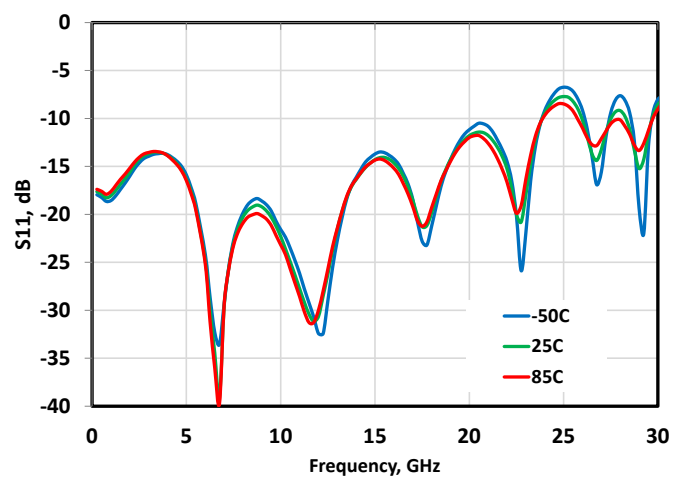
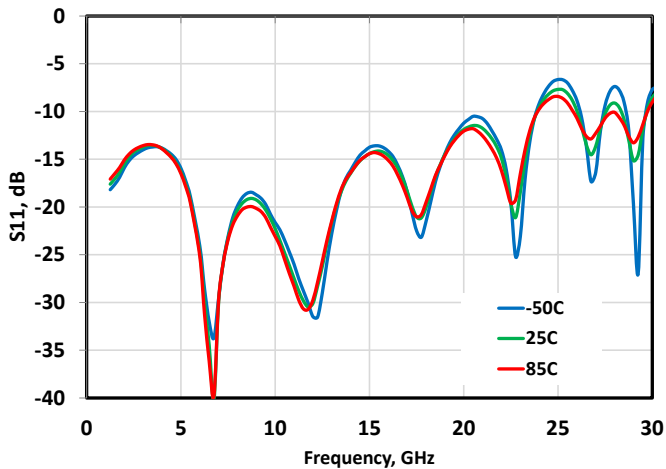
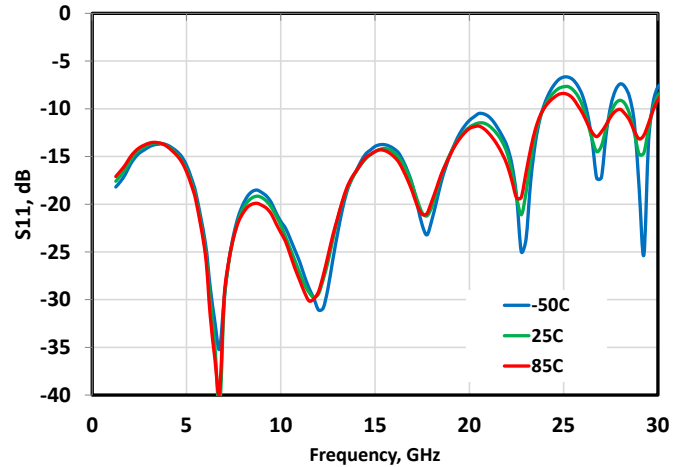
Figure 3 - Gain vs. Temperature @ 9V/310mA**Figure 4 - Gain vs. Temperature @ 10V/360mA****Figure 5 - S11 vs. Temperature @ 5V/220mA****Figure 6 - S11 vs. Temperature @ 8V/270mA****Figure 7 - S11 vs. Temperature @ 9V/310mA****Figure 8 - S11 vs. Temperature @ 10V/360mA**

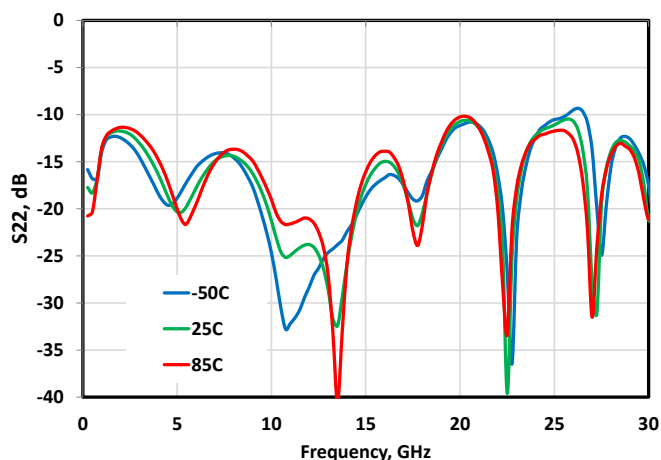
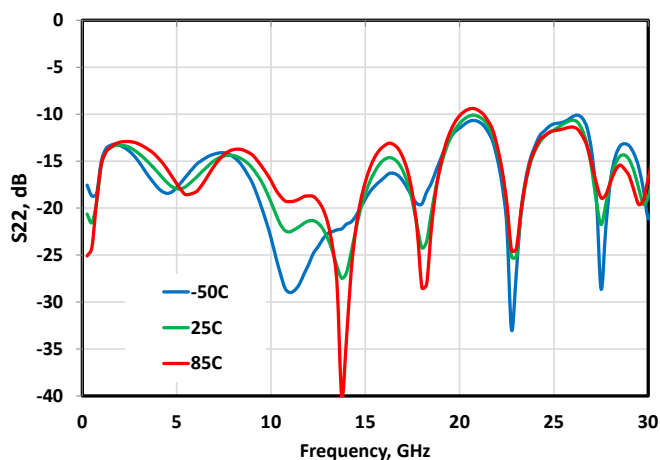
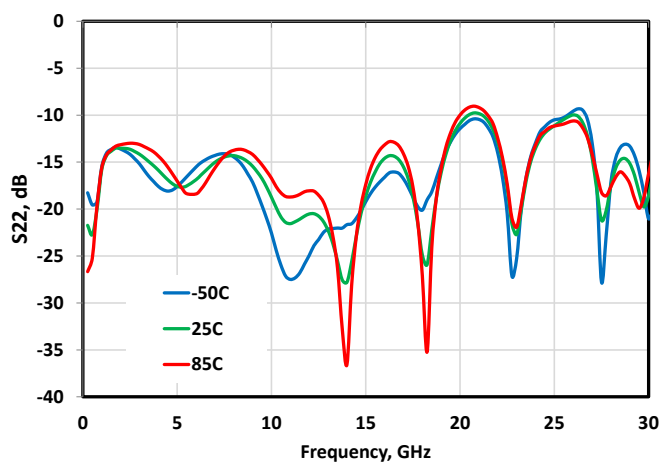
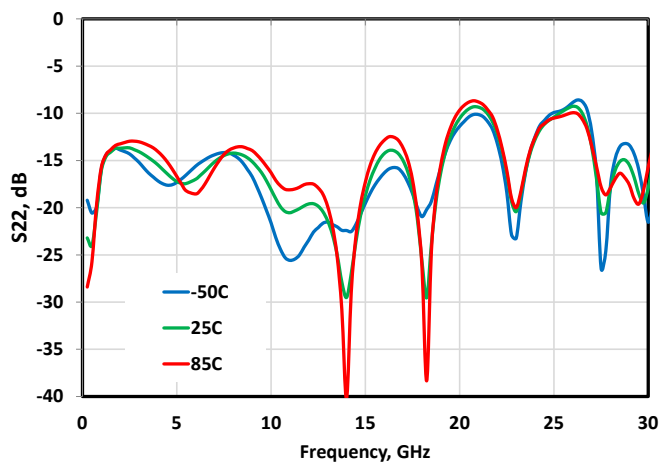
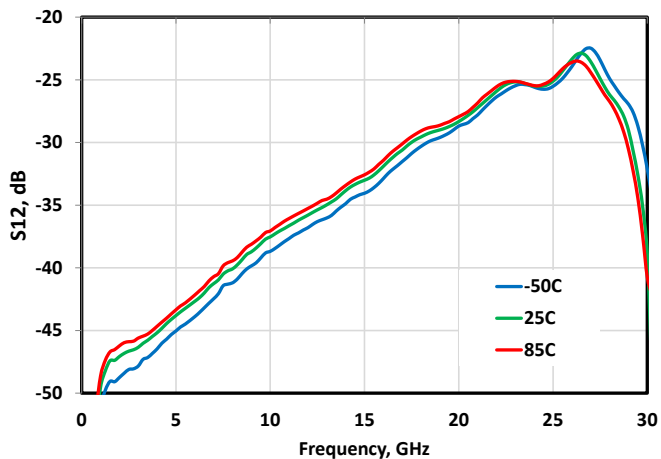
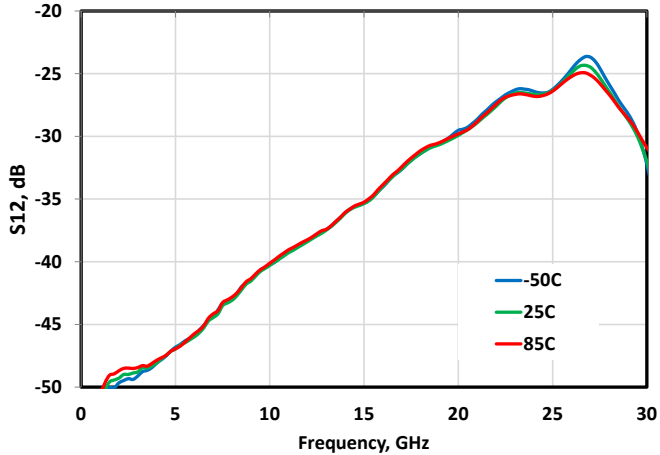
Figure 9 - S_{22} vs. Temperature @ 5V/220mA**Figure 10 - S_{22} vs. Temperature @ 8V/270mA****Figure 11 - S_{22} vs. Temperature @ 9V/310mA****Figure 12 - S_{22} vs. Temperature @ 10V/360mA****Figure 13 - S_{12} vs. Temperature @ 5V/220mA****Figure 14 - S_{12} vs. Temperature @ 8V/270mA**

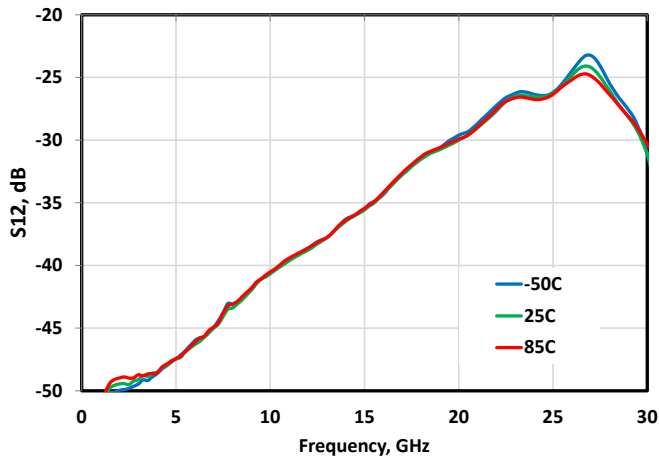
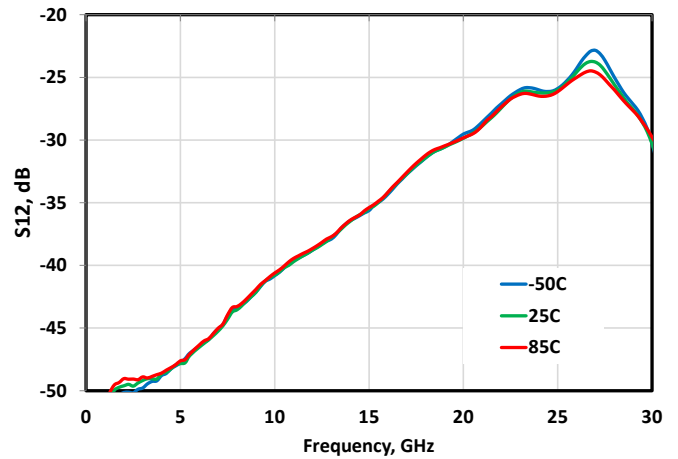
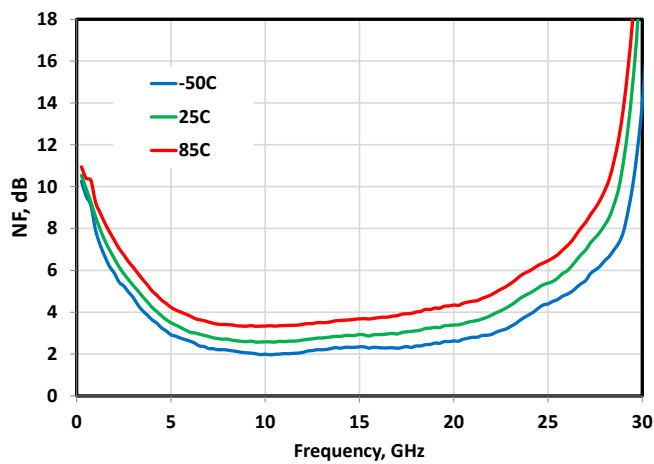
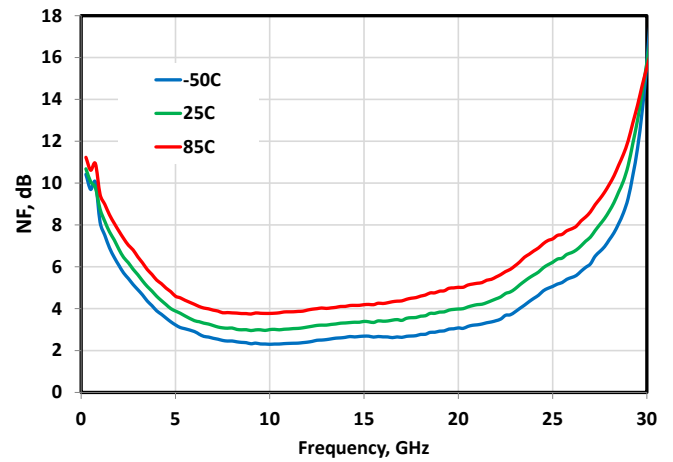
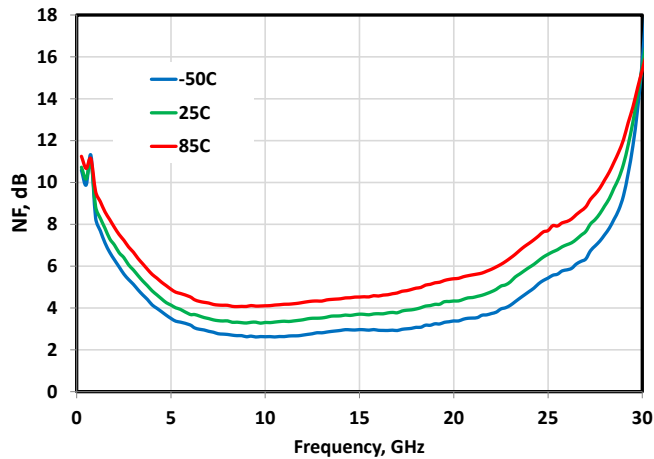
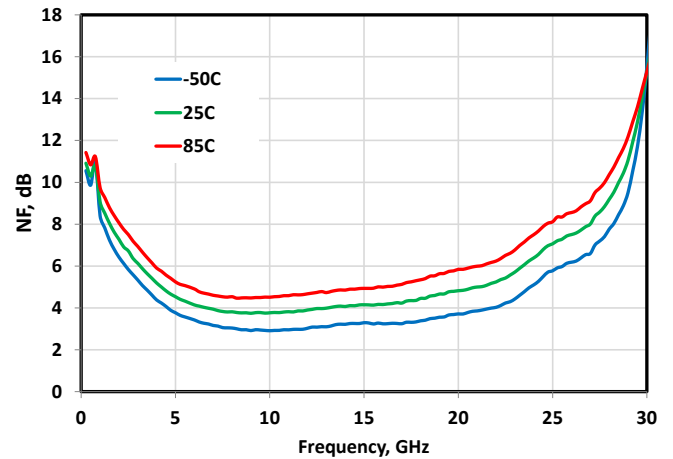
Figure 15 - S12 vs. Temperature @ 9V/310mA*Figure 16 - S12 vs. Temperature @ 10V/360mA**Figure 17 - NF vs. Temperature @ 5V/220mA**Figure 18 - NF vs. Temperature @ 8V/270mA**Figure 19 - NF vs. Temperature @ 9V/310mA**Figure 20 - NF vs. Temperature @ 10V/360mA*

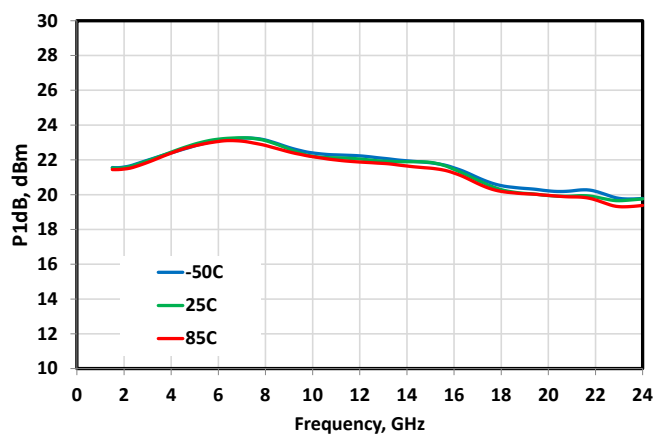
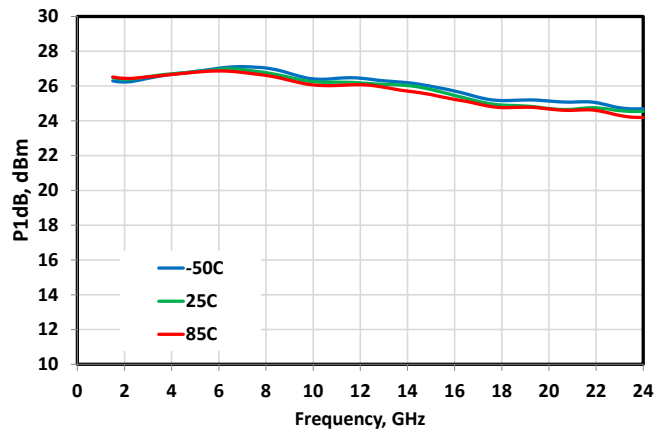
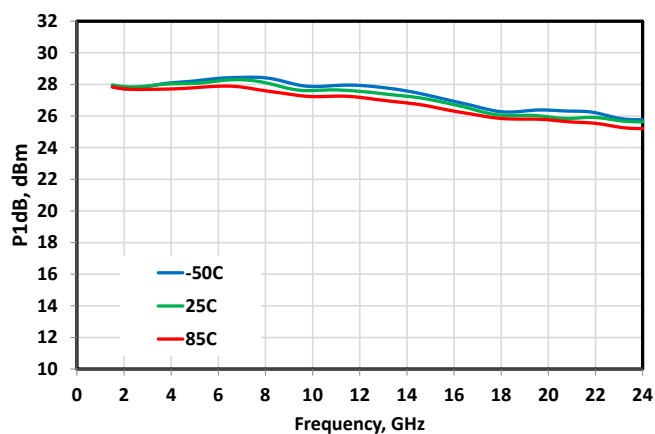
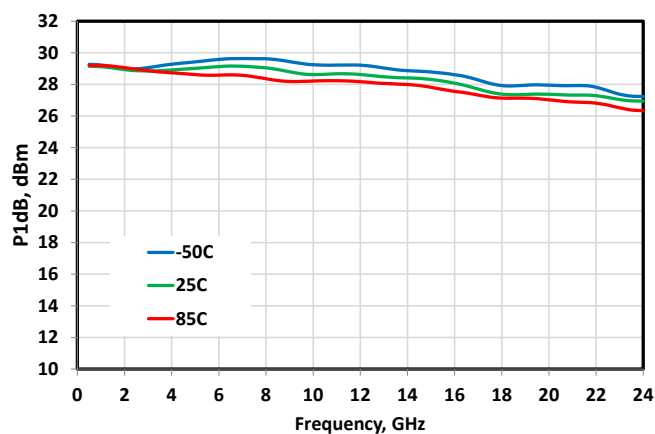
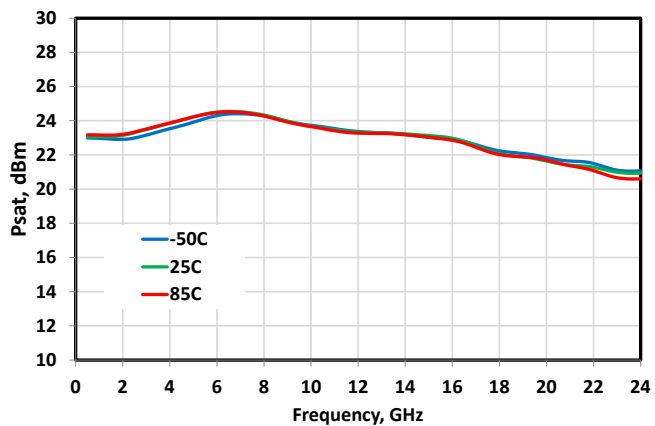
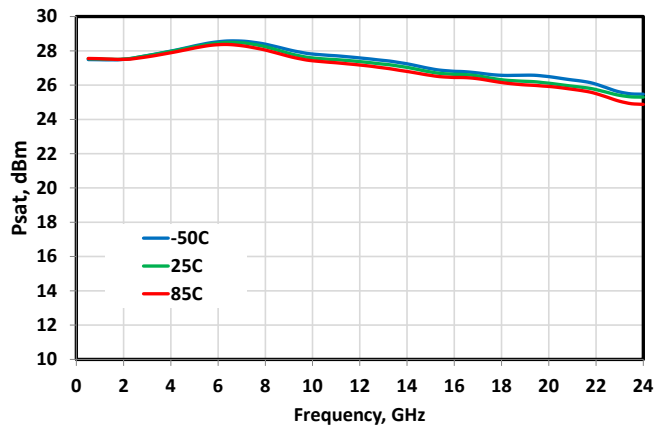
Figure 21 - P1dB vs. Temperature @ 5V/220mA*Figure 22 - P1dB vs. Temperature @ 8V/270mA**Figure 23 - P1dB vs. Temperature @ 9V/310mA**Figure 24 - P1dB vs. Temperature @ 10V/360mA**Figure 25 - Psat vs. Temperature @ 5V/220mA**Figure 26 - Psat vs. Temperature @ 8V/270mA*

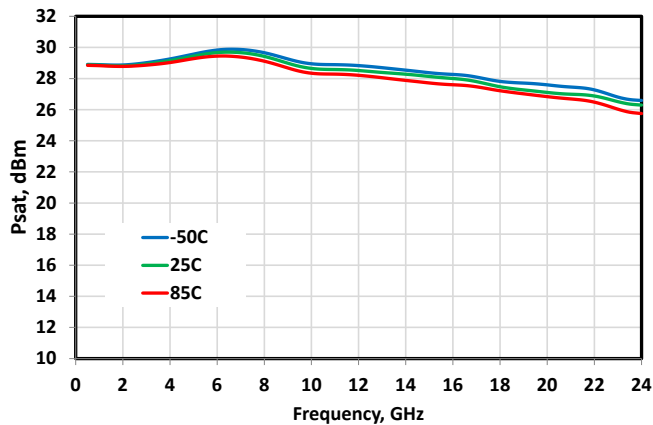
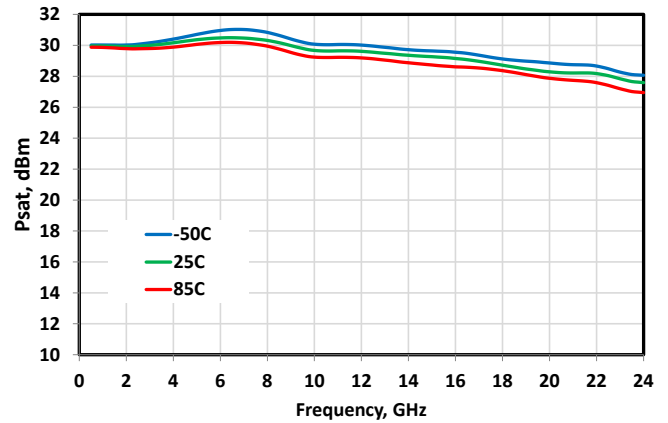
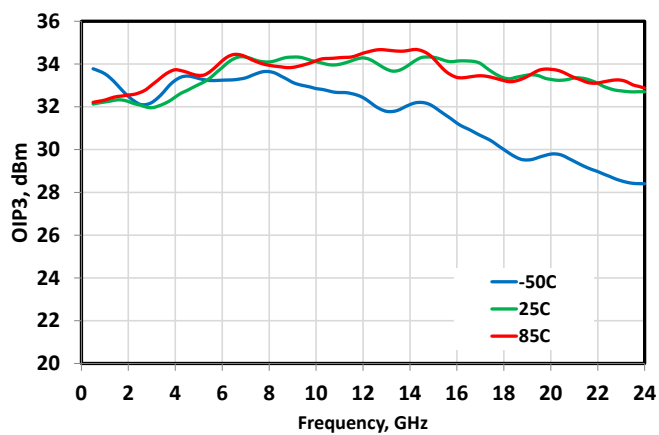
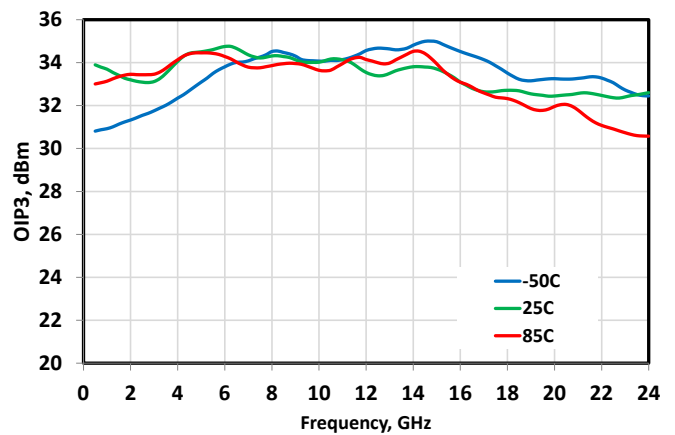
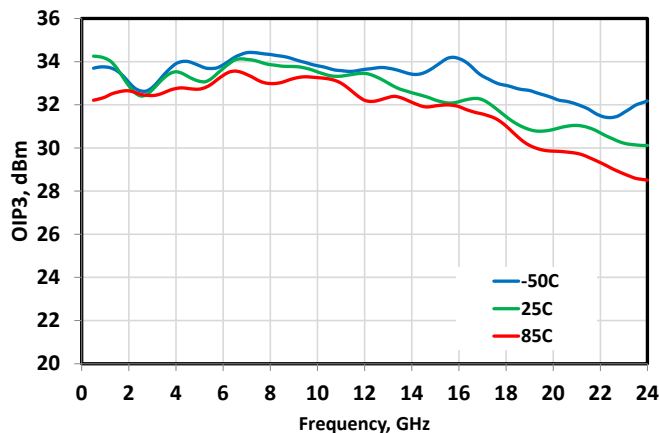
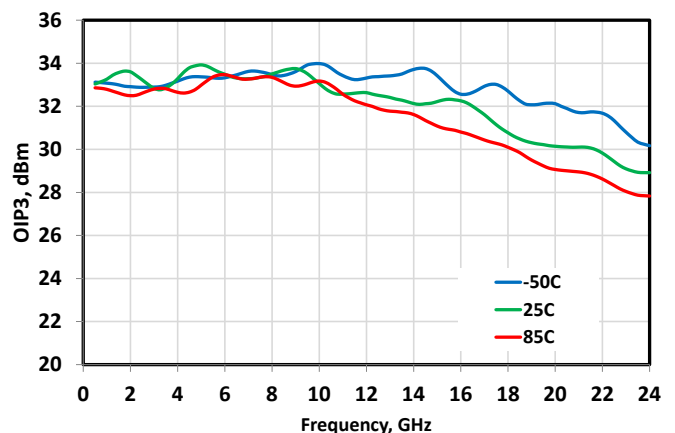
Figure 27 - P_{sat} vs. Temperature @ 9V/310mA**Figure 28 - P_{sat} vs. Temperature @ 10V/360mA****Figure 29 - $OIP3$ vs. Temperature @ 5V/220mA****Figure 30 - $OIP3$ vs. Temperature @ 8V/270mA****Figure 31 - $OIP3$ vs. Temperature @ 9V/310mA****Figure 32 - $OIP3$ vs. Temperature @ 10V/360mA**

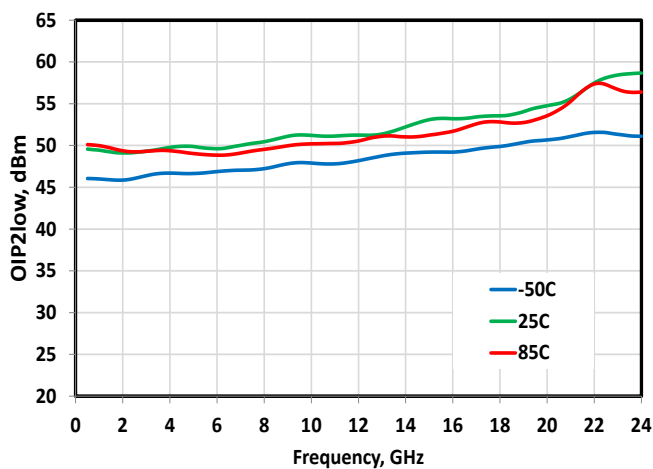
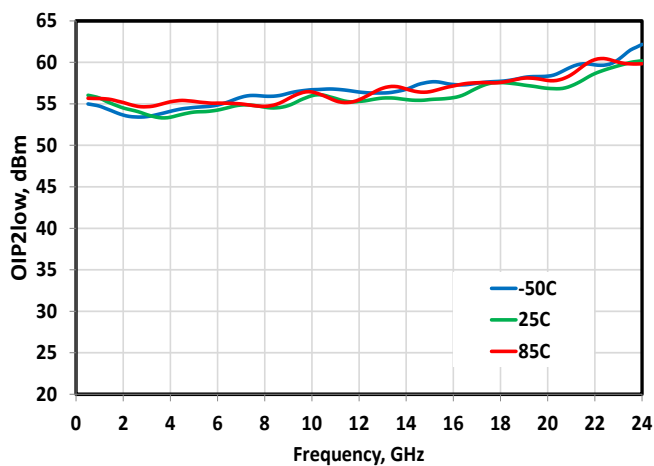
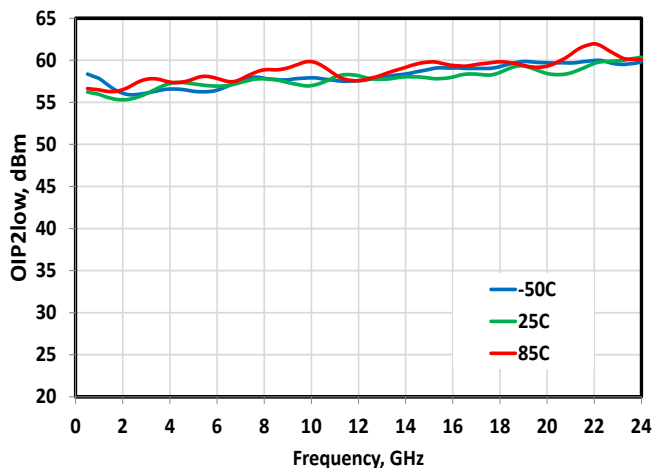
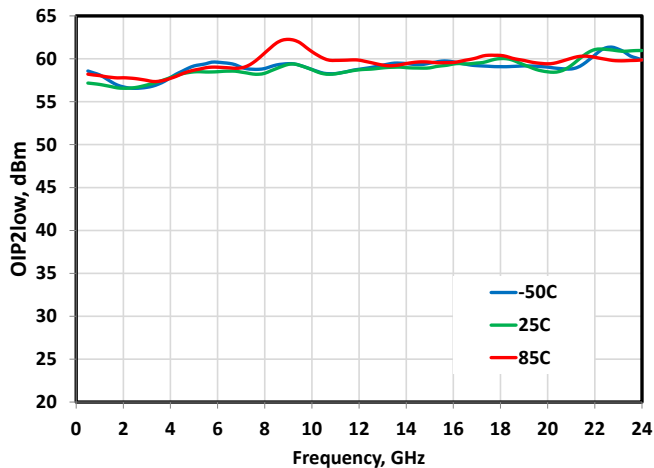
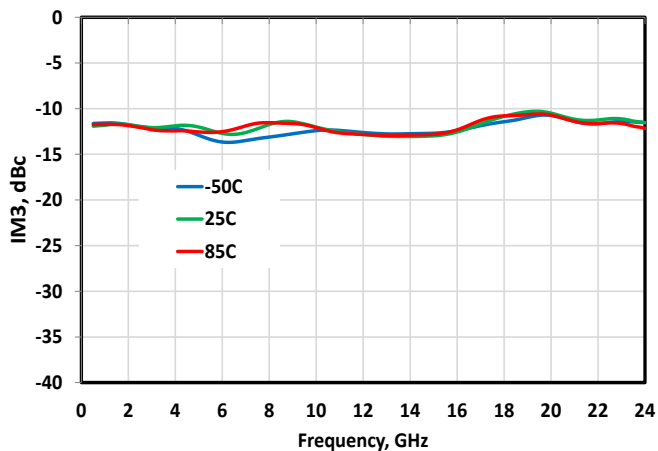
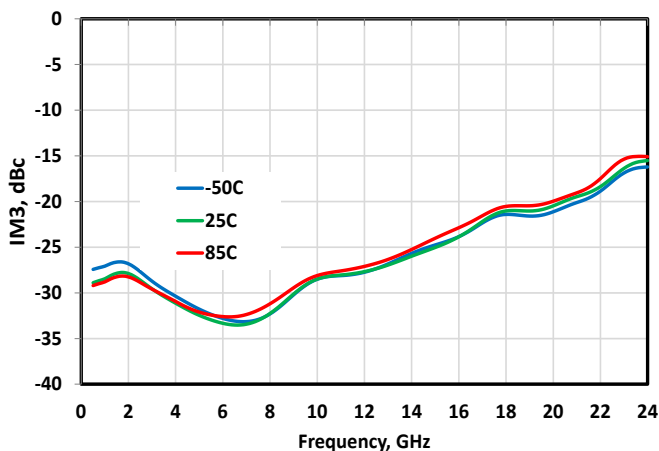
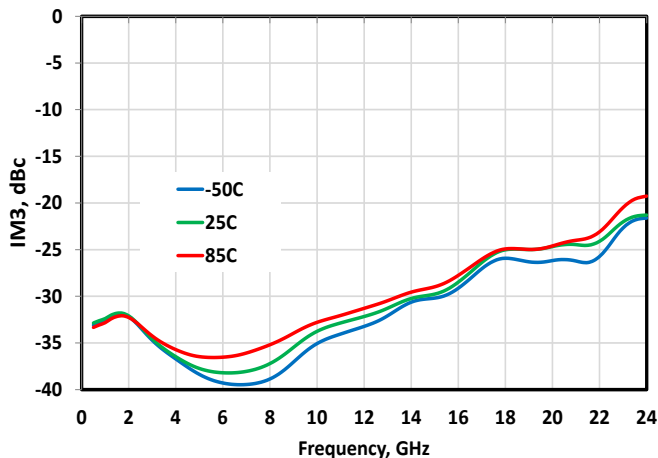
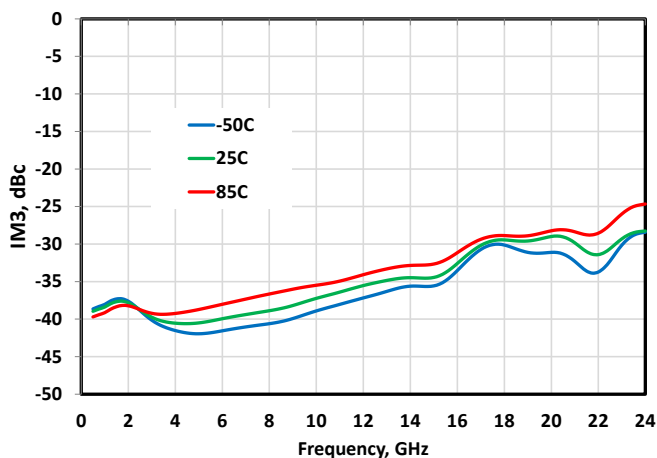
Figure 33 - OIP2(low) vs. Temperature @ 5V/220mA**Figure 34 - OIP2(low) vs. Temperature @ 8V/270mA****Figure 35 - OIP2(low) vs. Temperature @ 9V/310mA****Figure 36 - OIP2(low) vs. Temperature @ 10V/360mA****Figure 37 - IM3 vs. Temperature @ 5V/220mA, 20dBm(per tone)****Figure 38 - IM3 vs. Temperature @ 8V/270mA, 20dBm(per tone)**

Figure 39 - IM3 vs. Temperature @ 9V/310mA, 20dBm(per tone)**Figure 40 - IM3 vs. Temperature @ 10V/360mA, 20dBm(per tone)**

1.1.2 Typical Performances vs. Bias

The following graphs show the typical performance curves of the MMA052PP45 device at 25 °C vs. Bias conditions; measurements performed using application circuit shown on Figure 71 - below. Currents were set by States according to Table 3-3

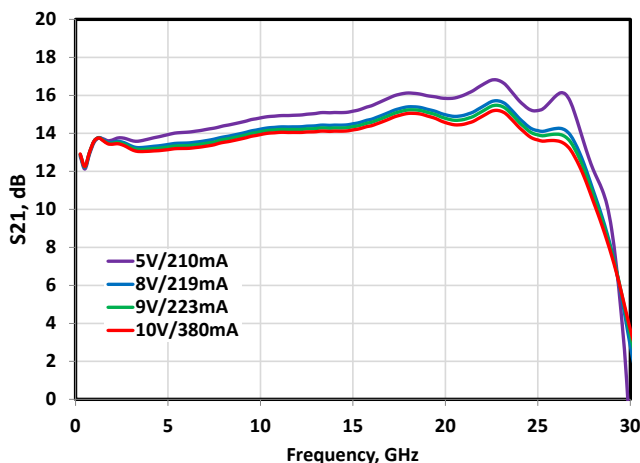
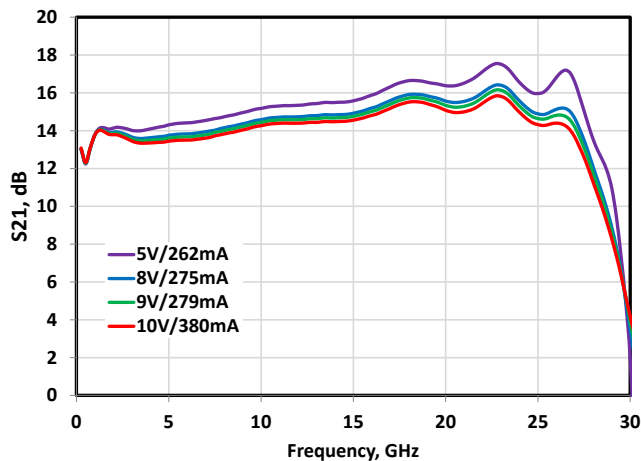
Figure 41 - Gain vs. V_{DD} @ State 1**Figure 42 - Gain vs. V_{DD} @ State 5**

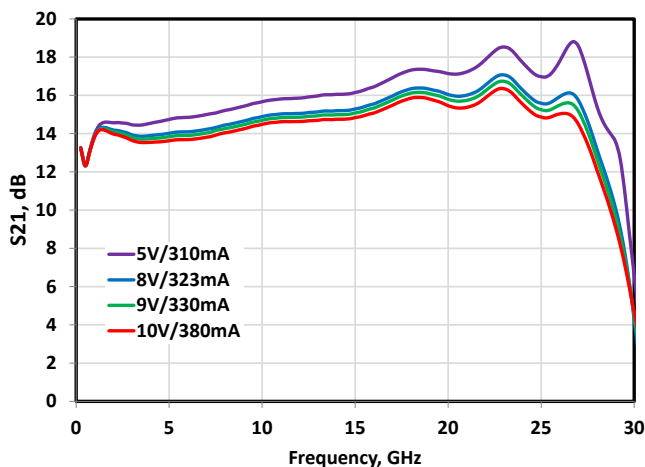
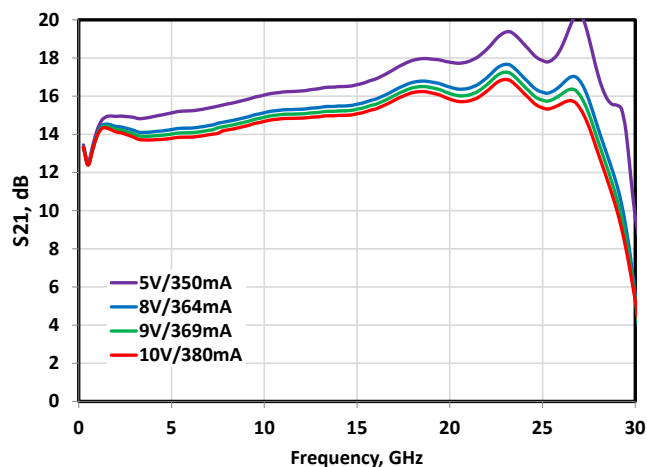
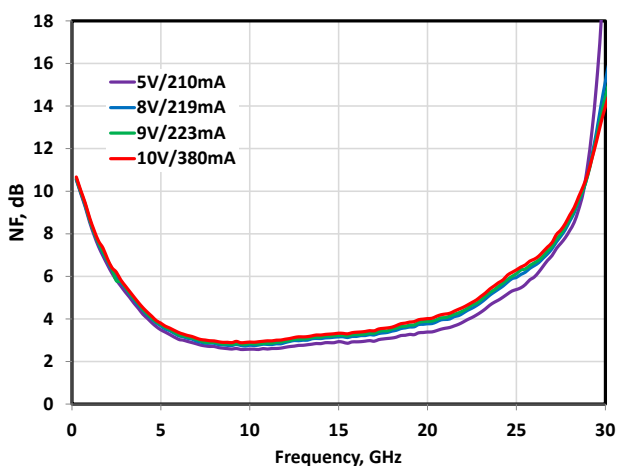
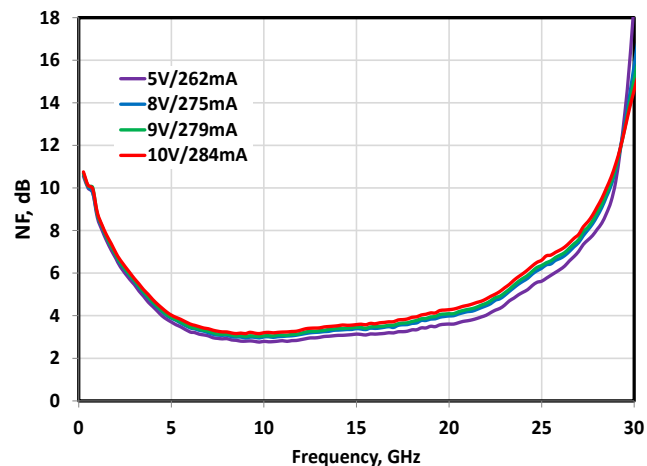
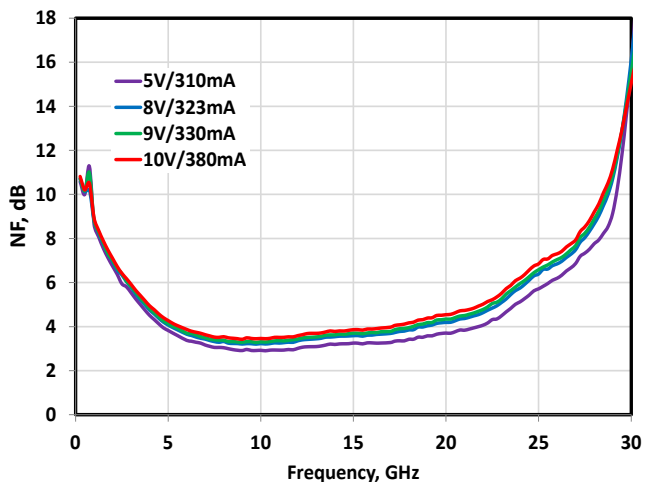
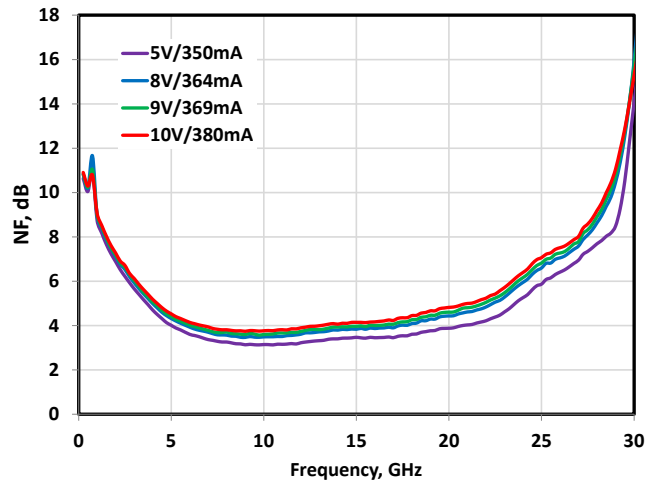
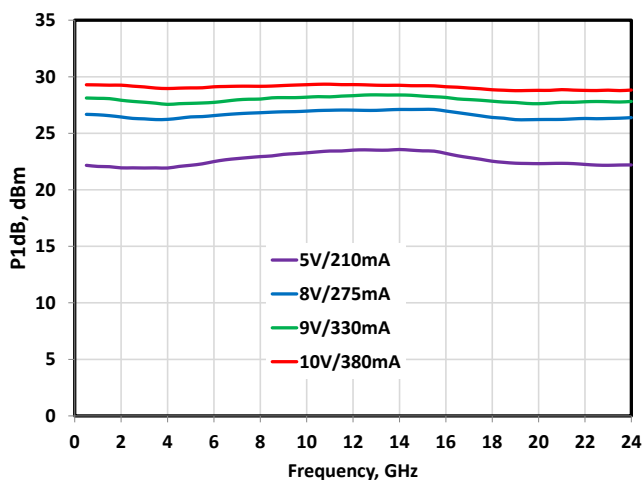
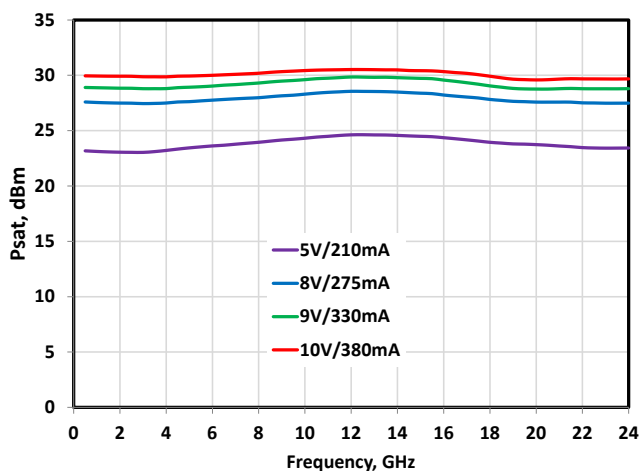
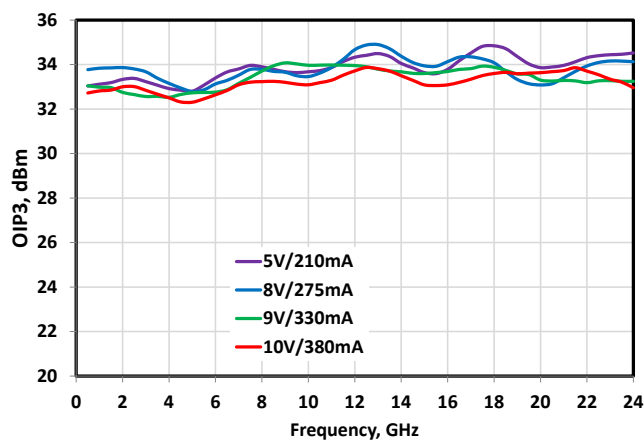
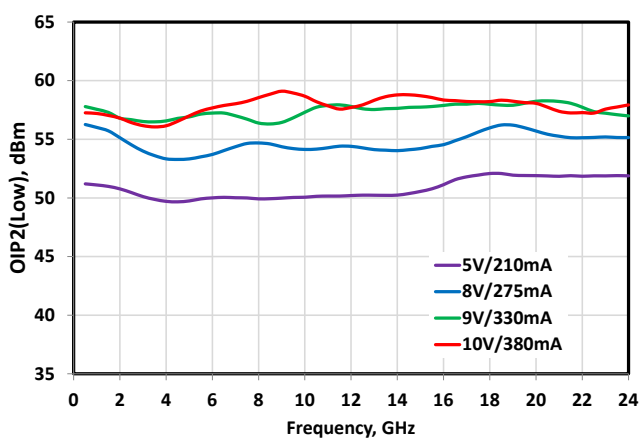
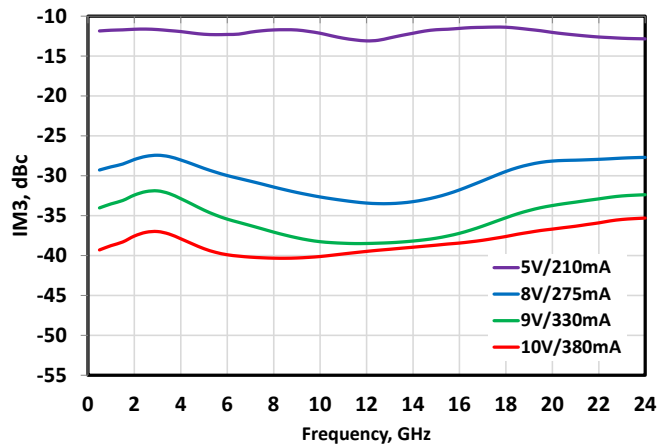
Figure 43 - Gain vs. V_{DD} @ State 8*Figure 44 - Gain vs. V_{DD} @ State 16**Figure 45 - NF vs. V_{DD} @ State 1**Figure 46 - NF vs. V_{DD} @ State 5**Figure 47 - NF vs. V_{DD} @ State 8**Figure 48 - NF vs. V_{DD} @ State 16*

Figure 49 - $P1dB$ vs. V_{DD}/I_{DD} **Figure 50 - $Psat$ vs. V_{DD}/I_{DD}** **Figure 51 - $OIP3$ vs. V_{DD}/I_{DD}** **Figure 52 - $OIP2$ Low $\Delta t = 10MHz$ vs. V_{DD}/I_{DD}** **Figure 53 - $IM3$ vs. V_{DD}/I_{DD} , 20dBm(per tone)**

1.1.3 Typical Performances vs. Output Power

The following graphs show the typical performance curves of the MMA052PP45 device at 25 °C vs. Bias conditions, measurements performed using application circuit shown on Figure 71 - below. Currents were set by States according to Table 3-3

Figure 54 - IM2 v s. Power @ 5V/220mA

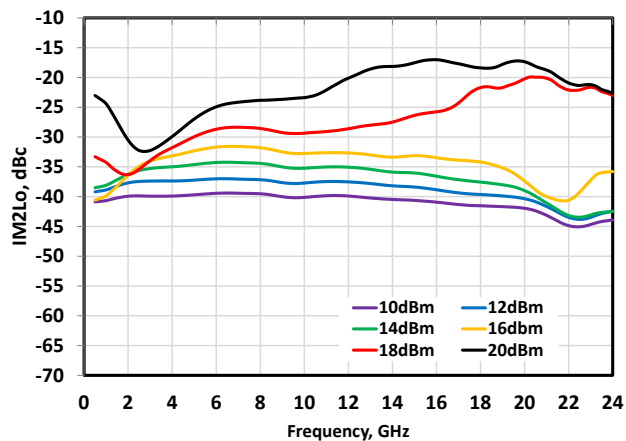


Figure 55 - IM2 vs. Power @ 8V/270mA

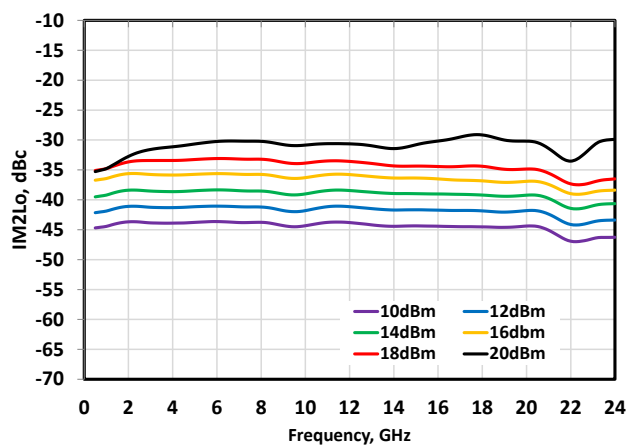


Figure 56 - IM2 vs. Power @ 9V/310mA

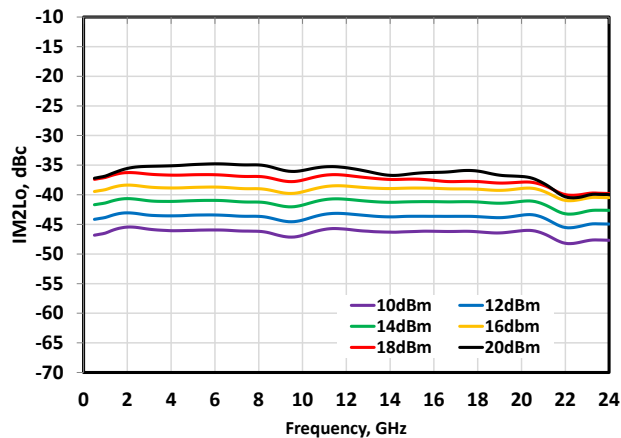


Figure 57 - IM2 vs. Power @ 10V/360mA

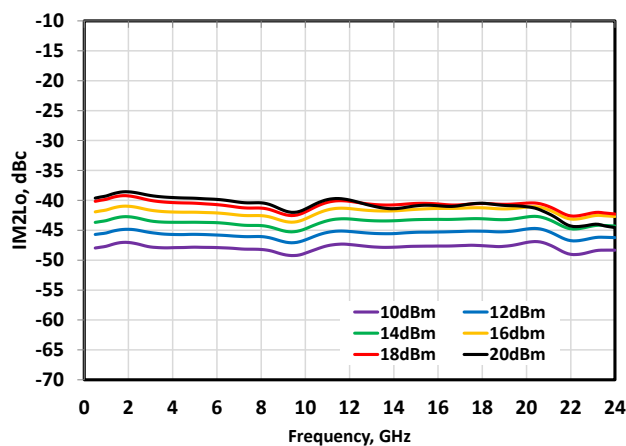


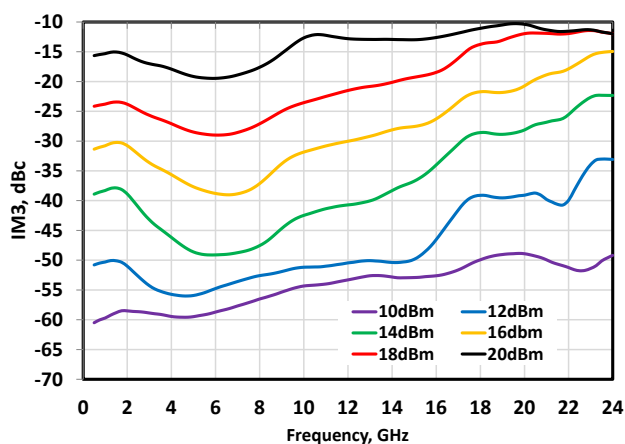
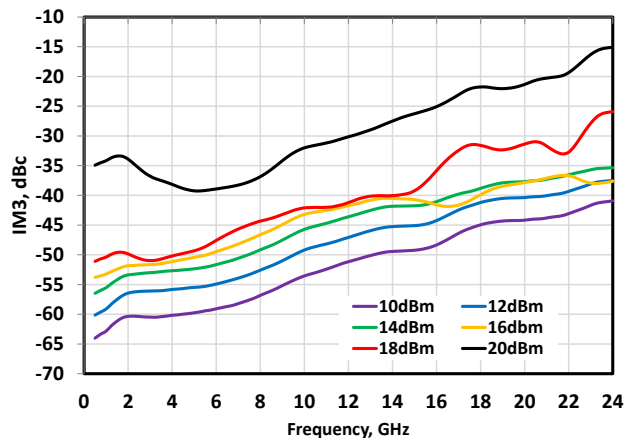
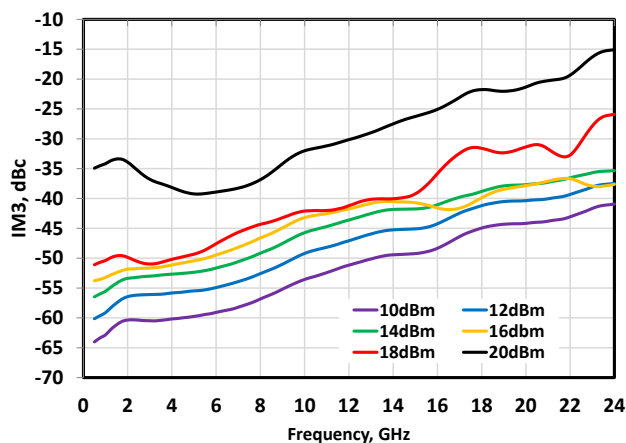
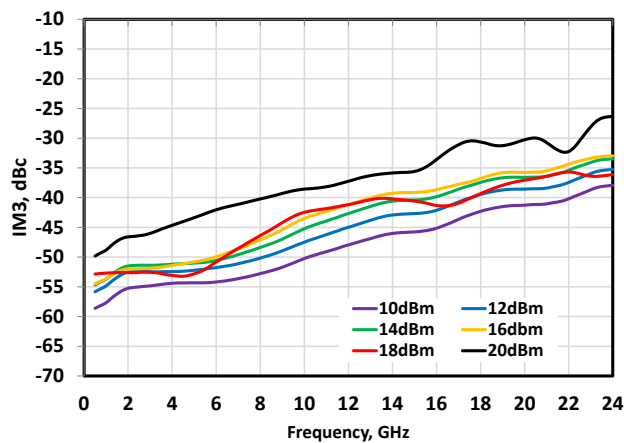
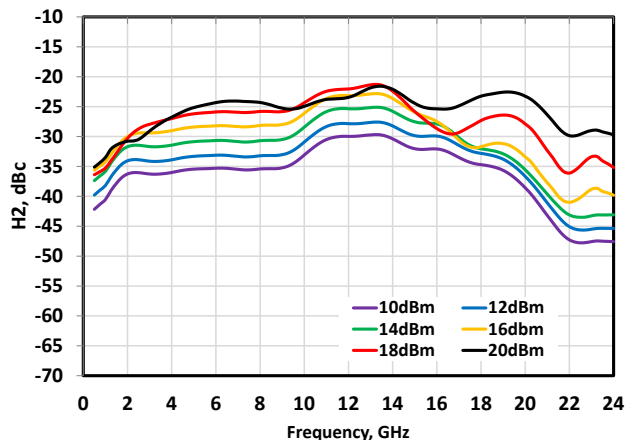
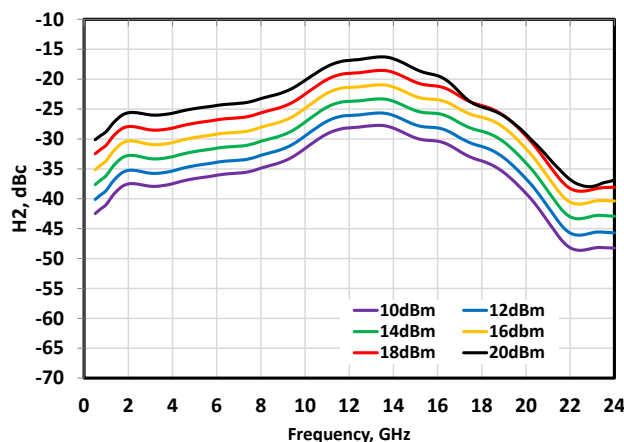
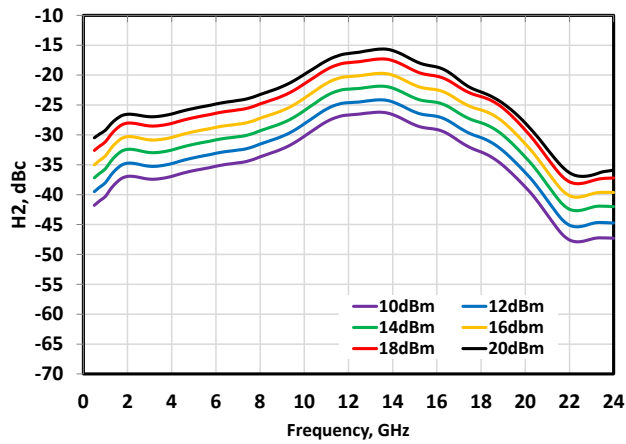
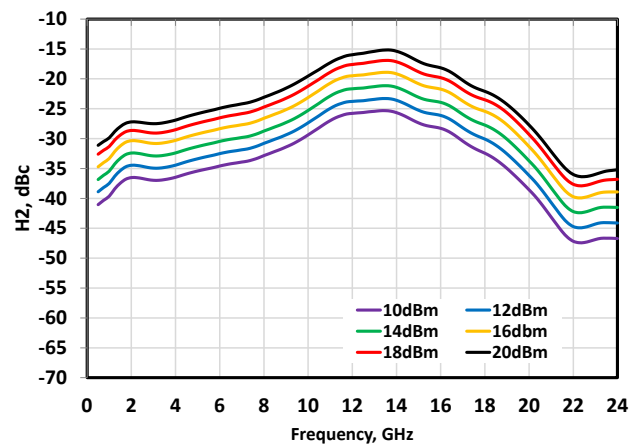
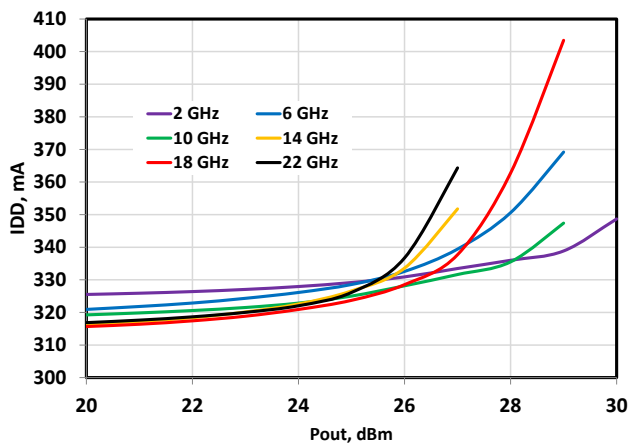
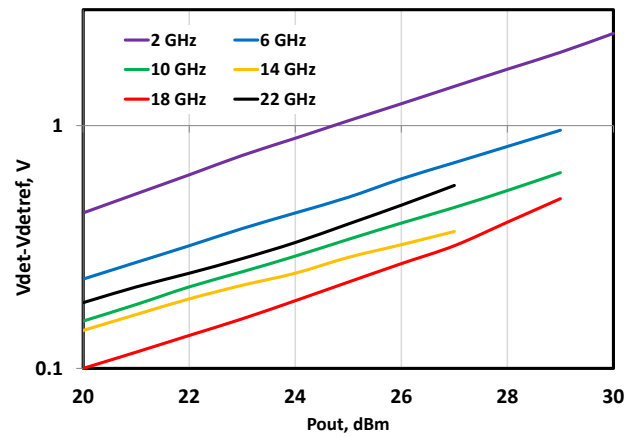
Figure 58 - IM3 vs. Power @ 5V/220mA**Figure 59 - IM3 vs. Power @ 8V/270mA****Figure 60 - IM3 vs. Power @ 9V/310mA****Figure 61 - IM3 vs. Power @ 10V/360mA****Figure 62 - 2-nd Harmonic vs. Power @ 5V/220mA****Figure 63 - 2-nd Harmonic vs. Power @ 8V/270mA**

Figure 64 - 2-nd Harmonic vs. Power @ 9V/310mA**Figure 65 - 2-nd Harmonic vs. Power @ 10V/360mA****Figure 66 - I_{DD} Current vs. Power, at 10V****Figure 67 - $V_{DET}-V_{DETREF}$ vs. Power**

2. Package Specifications

The following illustration shows the package outline of the MMA052PP45 device. Dimensions are in millimeters [inches].

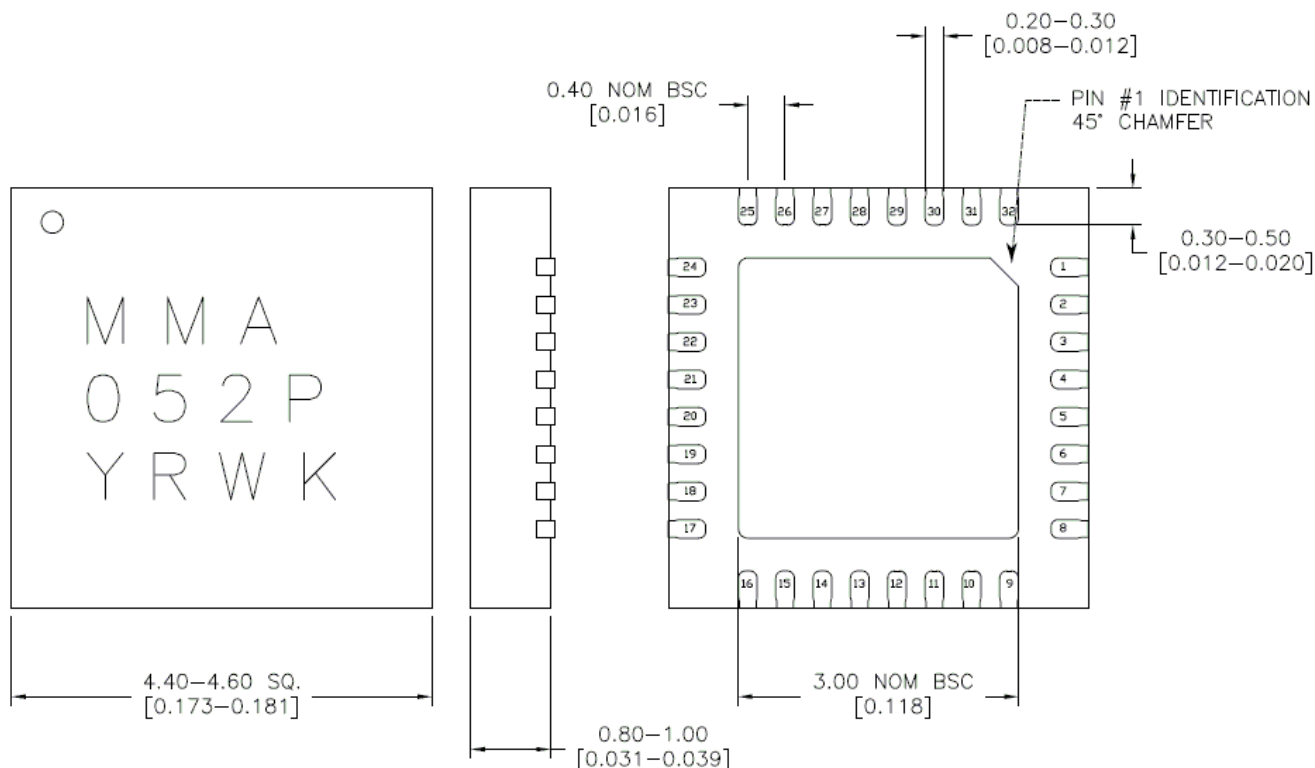


Figure 68 - Die Outline Drawing (mm)

Table 3 - I/O Description

Package	4.5mm X 4.5mm 32L Plastic QFN
Lead Frame	C194 Cu
Plating	Ni/Pd/Au
Package Body Material	RoHS Compliant Low-stress injection molded plastic

Table 4 - I/O Description

Pad Number	Pad Name	Pad Description
4, 5	RF _{IN}	Pin 4 and 5 must be merged on the layout and are matched to 50 Ω, and DC coupled to gate 1. (See figure 3-3 layout pattern.)
21, 22	RF _{OUT}	Pin 21 and 22 must be merged on the layout and are matched to 50 Ω, These pins are used for VDD Bias. (See figure 3-3 layout pattern.)
1	V _{GG}	Bias for VG2, must be coupled to VDD by connecting it to VDA or VDB externally for nominal operation (Alternately, this pin could be used for gain/linearity fine tuning)
10, 12, 14, 16	V _{SB}	Self-biasing resistors terminals, to adjust bias current by shorting one or several to the ground (see Table 3.3), if not used Die will operate with it's default current (about 200mA)
28	V _{DET}	Detector pin, with DC voltage as function of output power, for correct operation of detector use VDET-VDETREF at external comparator
29	V _{DETREF}	Detector reference voltage

30, 32	V_{DA}, V_{DB}	DC linked to VDD internally. External bypass capacitors are required to extend RF match and gain flatness below 2 GHz. Not intended for VDD bias
3, 6, 20, 23, Middle Pad	Ground	Should be connected to RF/DC ground with as many vias as possible, see our recommended landing pattern as example
2, 7, 8, 9, 11, 13, 15, 17, 18, 19, 24, 25, 26, 27 & 31	N/C	These pins are not connected internally. All data was measured with these pins connected to RF/DC ground externally.

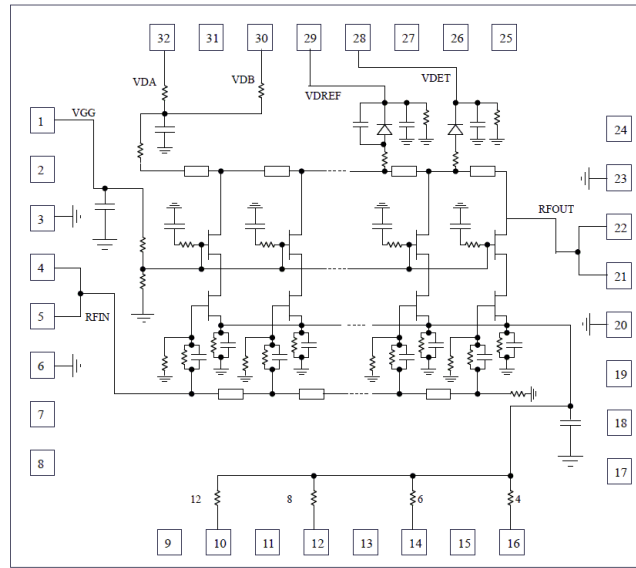


Figure 69 - Amplifier Functional Schematic

3. Application Circuits: Eval PCB

The following illustration shows the application circuit of the MMA052PP45E device. Note that there is no internal DC blocking capacitor on the input or the output, and a bias tee must be used on pin # 21 for biasing VDD

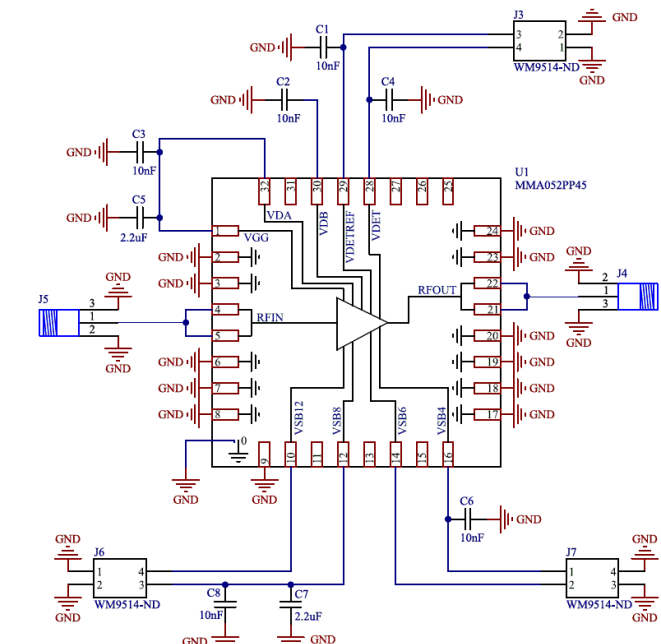
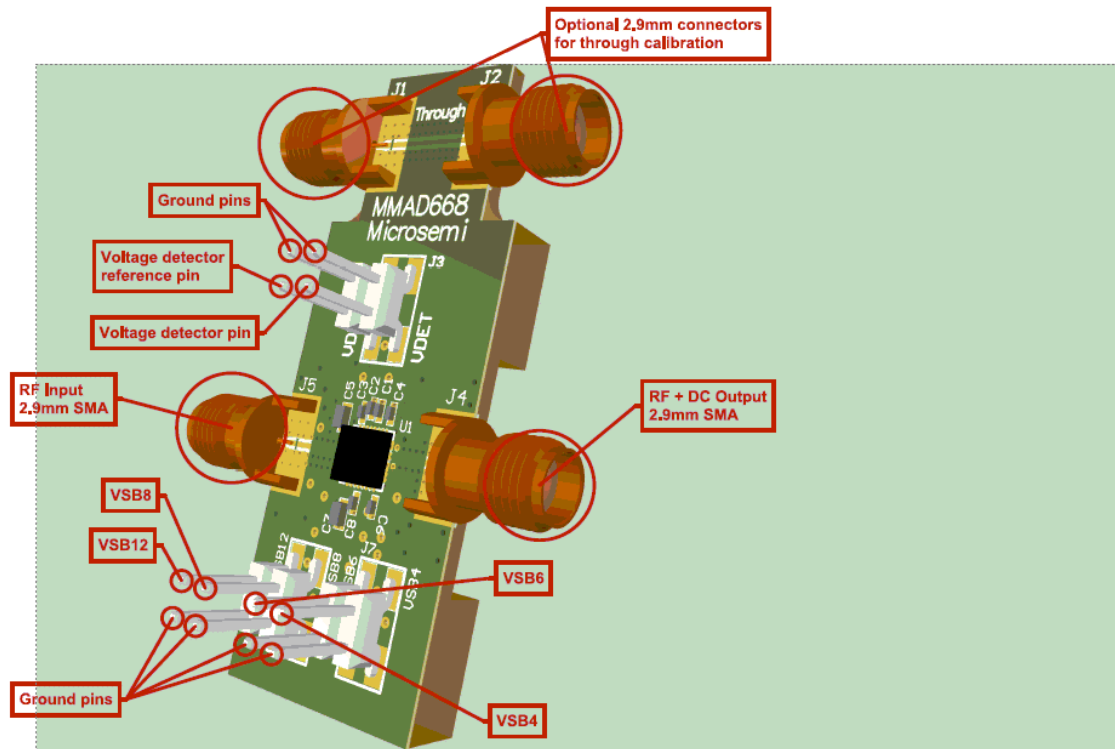


Figure 70 - MMA052PP45 Evaluation PCB

**Figure 71 - Evaluation PCB**

On the bottom two connectors where pins are labeled VSB12 through VSB4, the top row are connected internally to resistors that will change the drain current. The second row of pins below VSB12 through VSB4 are grounded. To use the different resistors in combinations to change the drain current jump the VSB pin to a ground pin as shown above. The average drain current values are listed below in table

Table 3-2. Bill of Material

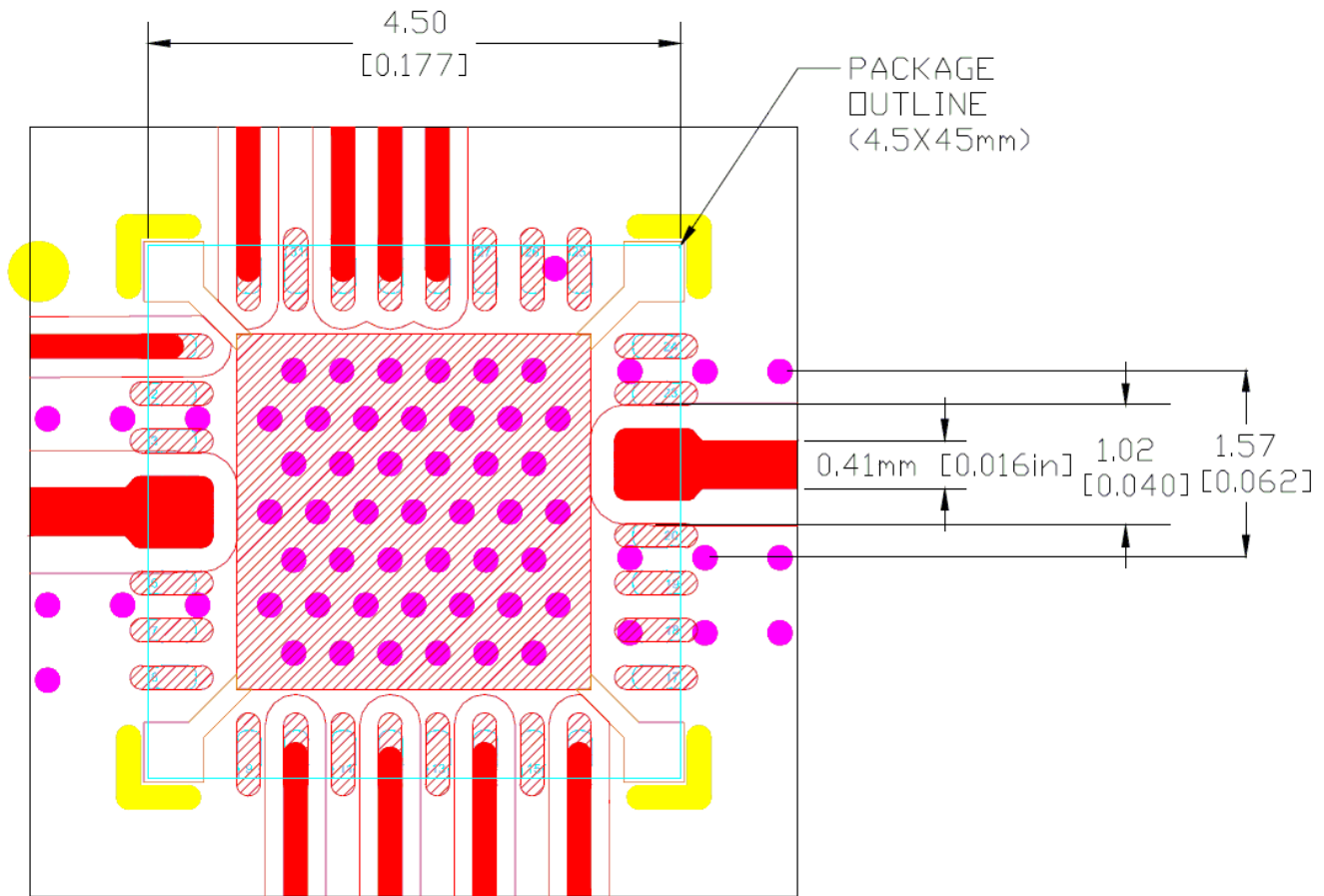
Item Num.	Component designator	Description	Mnf. Part Num.	Mnf.	Qty.
1	U1	4.5 X 4.5 32 Leads QFN	MMA052PP45	Microchip	1
2	C1, C2, C3, C4, C6, C8	10000 pF $\pm 10\%$ 50V Ceramic Capacitor X7R 0402	GRM155R71H10 3KA88D	Murata	6
3	C5, C7	2.2 μ F $\pm 10\%$ 16V Ceramic Capacitor X5R 0603	GRM21BR71C22 5KA12L	Murata	2
4	J1, J2, J4, J5	Connector, 2.9mm Jack PCB Edge Mount .012 pin	25-146-1000-90	Winchester Interconnect	4
5	J3, J6, J7	Header, 2-Pin, Dual row	15-91-2040	Molex	3

Table 3.2 MMA052PP45E Bias Sequence

Step	Bias Sequence
1	Make sure all DC and RF connections are attached before activating any DC voltage or supplies.
	Note: DC supply for VDD should be fed through an external bias-T on the RF+ DC output port (J4).
2	Make sure RF input port has no DC supplied to it as it will be terminated to grounded 50 Ohm.
3	Set VDD at 10.0V with current compliance at 400mA.
4	Use short jumpers on J6 and J7 headers to set IDD using internal resistors.
	Note: To short a resistor pin, connect a jumper to the ground pin below it.
	There are five combinations (always measure IDD current). 1. No jumpers (default IDD current = 200mA) 2. Jumper on VSB12: grounding 12Ohm resistor 3. Jumper on VSB8: grounding 8Ohm resistor 4. Jumper on VSB6: grounding 6Ohm resistor 5. Jumper on VSB4: grounding 4Ohm resistor Note: Use combination of jumpers to set required IDD current according to Table below.
	CAUTION: ENSURE NOT TO SHORT VDET OR VDETREF PINS TO AVOID DAMAGE TO PART

Table 3.3 IDD currents vs VSB positioning States at different Voltages VDD

State	V _{SB12}	V _{SB8}	V _{SB6}	V _{SB4}	I _{DD} at 5V	I _{DD} at 8V	I _{DD} at 9V	I _{DD} at 10V
1	Open	Open	Open	Open	208	219	223	227
2	Short	Open	Open	Open	237	249	253	258
3	Open	Short	Open	Open	250	262	267	271
4	Short	Short	Open	Open	273	285	290	295
5	Open	Open	Short	Open	262	275	279	284
6	Short	Open	Short	Open	284	296	301	306
7	Open	Short	Short	Open	293	306	311	316
8	Short	Short	Short	Open	310	323	328	334
9	Open	Open	Open	Short	283	296	301	306
10	Short	Open	Open	Short	302	315	320	326
11	Open	Short	Open	Short	310	324	329	335
12	Short	Short	Open	Short	325	339	344	351
13	Open	Open	Short	Short	318	332	337	343
14	Short	Open	Short	Short	332	346	351	358
15	Open	Short	Short	Short	339	352	357	364
16	Short	Short	Short	Short	350	364	369	376

Figure 3-3. MMA052PP45 Landing Pattern (mm[inch])

4. Handling Recommendations

Gallium arsenide integrated circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. It is recommended to follow all procedures and guidelines outlined in the Microsemi application note AN01: GaAs MMIC Handling and Die Attach Recommendations.

5. Ordering Information

For additional ordering information, contact your Microchip sales representative.

Part Number	Package
MMA052AA	Die
MMA052PP45	Package Part
MMA052PP45E	Evaluation PCB

5.1 Packing Information

Part Number	Description
MMA052PP45-TR	Tape and Reel

The Microchip Website

Microchip provides online support via our website at www.microchip.com/. This website is used to make files and information easily available to customers. Some of the content available includes:

- **Product Support** – Data sheets and errata, application notes and sample programs, design resources, user's guides and hardware support documents, latest software releases and archived software
- **General Technical Support** – Frequently Asked Questions (FAQs), technical support requests, online discussion groups, Microchip design partner program member listing
- **Business of Microchip** – Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

Product Change Notification Service

Microchip's product change notification service helps keep customers current on Microchip products. Subscribers will receive email notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, go to www.microchip.com/pcn and follow the registration instructions.

Customer Support

Users of Microchip products can receive assistance through several channels:

- Distributor or Representative
- Local Sales Office
- Embedded Solutions Engineer (ESE)
- Technical Support Customers should contact their distributor, representative or ESE for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in this document.

Technical support is available through the website at: www.microchip.com/support

Microchip Devices Code Protection Feature

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods being used in attempts to breach the code protection features of the Microchip devices. We believe that these methods require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Attempts to breach these code protection features, most likely, cannot be accomplished without violating Microchip's intellectual property rights.
- Microchip is willing to work with any customer who is concerned about the integrity of its code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not mean that we are guaranteeing the product is "unbreakable." Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Legal Notice

Information contained in this publication is provided for the sole purpose of designing with and using Microchip products. Information regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY

OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL OR CONSEQUENTIAL LOSS, DAMAGE, COST OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Klear, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TempTrackr, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, Vite, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KlearNet, KlearNet logo, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2021, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved. ISBN:

Quality Management System

For information regarding Microchip's Quality Management Systems, please visit www.microchip.com/quality.

Worldwide Sales and Service

AMERICAS	ASIA/PACIFIC	ASIA/PACIFIC	EUROPE
Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: www.microchip.com/support Web Address: www.microchip.com Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455 Austin, TX Tel: 512-257-3370 Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088 Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075 Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924 Detroit Novi, MI Tel: 248-848-4000 Houston, TX Tel: 281-894-5983 Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380 Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800 Raleigh, NC Tel: 919-844-7510 New York, NY Tel: 631-435-6000 San Jose, CA Tel: 408-735-9110 Tel: 408-436-4270 Canada - Toronto Tel: 905-695-1980 Fax: 905-695-2078	Australia - Sydney Tel: 61-2-9868-6733 China - Beijing Tel: 86-10-8569-7000 China - Chengdu Tel: 86-28-8665-5511 China - Chongqing Tel: 86-23-8980-9588 China - Dongguan Tel: 86-769-8702-9880 China - Guangzhou Tel: 86-20-8755-8029 China - Hangzhou Tel: 86-571-8792-8115 China - Hong Kong SAR Tel: 852-2943-5100 China - Nanjing Tel: 86-25-8473-2460 China - Qingdao Tel: 86-532-8502-7355 China - Shanghai Tel: 86-21-3326-8000 China - Shenyang Tel: 86-24-2334-2829 China - Shenzhen Tel: 86-755-8864-2200 China - Suzhou Tel: 86-186-6233-1526 China - Wuhan Tel: 86-27-5980-5300 China - Xian Tel: 86-29-8833-7252 China - Xiamen Tel: 86-592-2388138 China - Zhuhai Tel: 86-756-3210040	India - Bangalore Tel: 91-80-3090-4444 India - New Delhi Tel: 91-11-4160-8631 India - Pune Tel: 91-20-4121-0141 Japan - Osaka Tel: 81-6-6152-7160 Japan - Tokyo Tel: 81-3-6880-3770 Korea - Daegu Tel: 82-53-744-4301 Korea - Seoul Tel: 82-2-554-7200 Malaysia - Kuala Lumpur Tel: 60-3-7651-7906 Malaysia - Penang Tel: 60-4-227-8870 Philippines - Manila Tel: 63-2-634-9065 Singapore Tel: 65-6334-8870 Taiwan - Hsin Chu Tel: 886-3-577-8366 Taiwan - Kaohsiung Tel: 886-7-213-7830 Taiwan - Taipei Tel: 886-2-2508-8600 Thailand - Bangkok Tel: 66-2-694-1351 Vietnam - Ho Chi Minh Tel: 84-28-5448-2100	Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen Tel: 45-4485-5910 Fax: 45-4485-2829 Finland - Espoo Tel: 358-9-4520-820 France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79 Germany - Garching Tel: 49-8931-9700 Germany - Haan Tel: 49-2129-3766400 Germany - Heilbronn Tel: 49-7131-72400 Germany - Karlsruhe Tel: 49-721-625370 Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44 Germany - Rosenheim Tel: 49-8031-354-560 Israel - Ra'anana Tel: 972-9-744-7705 Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781 Italy - Padova Tel: 39-049-7625286 Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340 Norway - Trondheim Tel: 47-72884388 Poland - Warsaw Tel: 48-22-3325737 Romania - Bucharest Tel: 40-21-407-87-50 Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91 Sweden - Gothenberg Tel: 46-31-704-60-40 Sweden - Stockholm Tel: 46-8-5090-4654 UK - Wokingham Tel: 44-118-921-5800 Fax: 44-118-921-5820

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Microchip:](#)

[MMA052PP45](#) [MMA052PP45TR](#)